

## Low capacitance diode array

#### **Features**

- Protection of 4 lines
- Peak reverse voltage: V<sub>RRM</sub> = 9 V per diode
- Very low capacitance per diode: C < 5 pF
- Very low leakage current: I<sub>R</sub> < 1 µA</p>

#### **Benefits**

- Cost-effective solution compared with discrete solution
- High efficiency in ESD suppression
- No significant signal distortion thanks to very low capacitance
- High reliability offered by monolithic integration
- Lower PCB area consumption versus discrete solution

#### Complies with the following standards

- IEC61000-4-2 level 4
- MIL STD 883G-Method 3015-7: class 3, human body model

## **Applications**

Where ESD and/or over and undershoot protection for datalines is required:

- Sensitive logic input protection
- Microprocessor based equipment
- Audio / video inputs
- Portable electronics
- Networks
- ISDN equipment
- USB interface

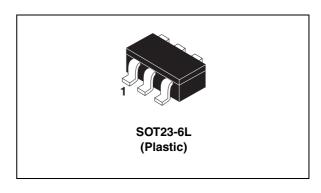
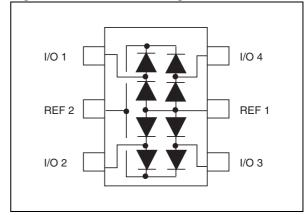


Figure 1. Functional diagram



## **Description**

The DALC208SC6 diode array is designed to protect components which are connected to data and transmission lines from over voltages caused by electrostatic discharge (ESD) or other transients. It is a rail-to-rail protection device also suited for overshoot and undershoot suppression on sensitive logic inputs.

The low capacitance of the DALC208SC6 prevents significant signal distortion.

Characteristics DALC208

## 1 Characteristics

Table 1. Absolute maximum ratings  $(T_{amb} = 25 \, ^{\circ}C)$ 

Symbol	Parameter	Value	Unit
$V_{PP}$	IEC61000-4-2, air discharge	15	kV
• PP	IEC61000-4-2, contact discharge	8	
$V_{RRM}$	Peak reverse voltage per diode	9	V
$\Delta V_{REF}$	Reference voltage gap between $V_{REF2}$ and $V_{REF1}$	9	V
V <sub>In</sub> max.	Maximum operating signal input voltage	V <sub>REF2</sub>	V
V <sub>In</sub> min.	Minimum operating signal input voltage	V <sub>REF1</sub>	V
I <sub>F</sub>	Continuous forward current (single diode loaded)	200	mA
I <sub>FRM</sub>	Repetitive peak forward current (t <sub>p</sub> = 5 ms, F = 50 kHz)	700	mA
	Surge non repetitive forward current - rectangular waveform (See curve on <i>Figure 3</i> .)		
I <sub>FSM</sub>	$t_p = 2.5 \ \mu s$	6	Α
	$t_p = 1 \mu s$	2	
	$t_p = 100 \ \mu s$	1	
T <sub>stg</sub>	Storage temperature range	-55 to + 150	°C
T <sub>j</sub>	Maximum junction temperature	150	°C

Table 2. Thermal resistance

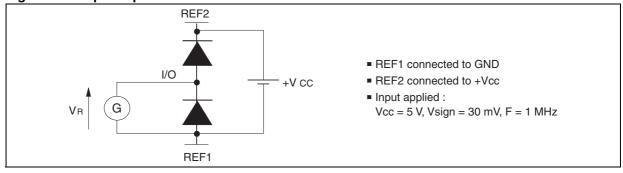
Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient <sup>(1)</sup>	500	°C/W

<sup>1.</sup> Device mounted on FR4 PCB with recommended footprint dimensions.

Table 3. Electrical characteristics ( $T_{amb} = 25 \, ^{\circ}C$ )

Symbol	Parameter	Conditions	Тур.	Max.	Unit
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 50 mA		1.2	V
I <sub>R</sub>	Reverse leakage current per diode	V <sub>R</sub> = 5 V		1	μΑ
С	Input capacitance between Line and GND	See Figure 2.	7	10	pF

Figure 2. Input capacitance measurement



DALC208 Characteristics

Figure 3. Maximum non-repetitive peak forward current versus rectangular pulse duration ( $T_i$  initial = 25 °C)

Figure 4. Reverse clamping voltage versus peak pulse current  $(T_j \text{ initial} = 25 \, ^{\circ}\text{C})$ , typical values. Rectangular waveform  $t_p = 2.5 \, \text{ms}$ 

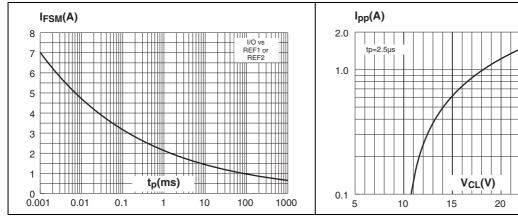


Figure 5. Variation of leakage current versus Figure 6. junction temperature (typical values)

Input capacitance versus reverse applied voltage (typical values)

I/O vs REF1 or REF2

25

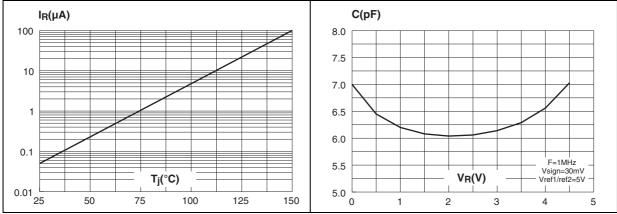
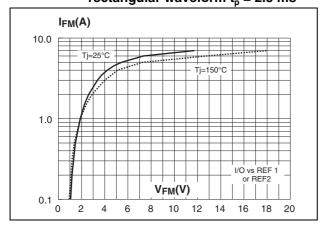


Figure 7. Peak forward voltage drop versus peak forward current (typical values), rectangular waveform  $t_n = 2.5 \text{ ms}$ 



Technical information DALC208

#### 2 Technical information

### 2.1 Surge protection

The DALC208SC6 is particularly optimized to perform surge protection based on the rail to rail topology.

The clamping voltage  $V_{\text{CL}}$  can be calculated as follow :

 $V_{CL}$ + =  $V_{REF2}$  +  $V_F$  for positive surges

 $V_{CL}$ - =  $V_{REF1}$  -  $V_F$  for negative surges

with

$$V_F = V_T + R_d.I_p$$

(V<sub>F</sub> forward drop voltage) / (V<sub>T</sub> forward drop threshold voltage)

According to the curve *Figure 7* we assume that the value of the dynamic resistance of the clamping diode is typically  $R_d = 0.7 \Omega$  and  $V_T = 1.2 \text{ V}$ .

For an IEC 61000-4-2 surge Level 4 (Contact Discharge:  $V_g$ =8 kV,  $R_g$ =330  $\Omega$ ),  $V_{REF2}$  = +5 V,  $V_{REF1}$  = 0 V, and if in first approximation, we assume that :  $I_p$  =  $V_g$  /  $R_g$  ′ 24 A.

So, we find:

- $V_{CI}+'+23V$
- V<sub>CI</sub>-'-18V

Note: The calculations do not take into account phenomena due to parasitic inductances.

## 2.2 Surge protection application example

If we consider that the connections from the pin REF $_2$  to V $_{\rm CC}$  and from REF $_1$  to GND are done by two tracks of 10 mm long and 0.5 mm large; we assume that the parasitic inductances of these tracks are about 6 nH. So when an IEC 61000-4-2 surge occurs, due to the rise time of this spike (tr = 1 ns), the voltage V $_{\rm Cl}$  has an extra value equal to Lw.dl/dt.

The dl/dt is calculated as: dl/dt = lp/tr ' 24 A/ns

The overvoltage due to the parasitic inductances is: Lw.dl/dt = 6 x 24 ' 144V

By taking into account the effect of these parasitic inductances due to unsuitable layout, the clamping voltage will be :

- $V_{CL}$ + = +23 + 144 ' 167V
- $V_{CI}$  = -18 144 ' -162V

We can reduce as much as possible these phenomena with simple layout optimization.

It's the reason why some recommendations have to be followed (See Section 2.3: How to ensure good ESD protection).

DALC208 Technical information

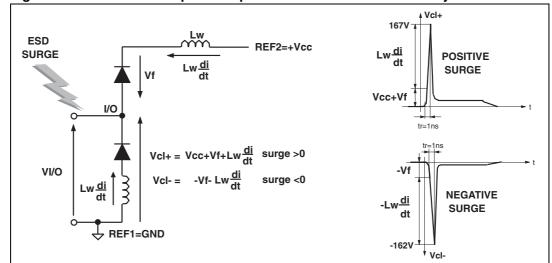


Figure 8. ESD behavior: parasitic phenomena due to unsuitable layout

### 2.3 How to ensure good ESD protection

While the DALC208SC6 provides a high immunity to ESD surge, an efficient protection depends on the layout of the board. In the same way, with the rail to rail topology, the track from the  $V_{REF2}$  pin to the power supply  $+V_{CC}$  and from the  $V_{REF1}$  pin to GND must be as short as possible to avoid over voltages due to parasitic phenomena. See *Figure 8*.

It's often harder to connect the power supply near to the DALC208SC6 unlike the ground thanks to the ground plane that allows a short connection.

To ensure the same efficiency for positive surges when the connections can't be short enough, we recommend putting a capacitance of 100 nF close to the DALC208SC6, between  $V_{\text{REF2}}$  and ground, to prevent these kinds of overvoltage disturbances. See *Figure 9*.

The addition of this capacitance will allow a better protection by providing a constant voltage during a surge.

Figure 10, Figure 11, and Figure 12 show the improvement of the ESD protection according to the recommendations described above.

Technical information DALC208

Figure 9. ESD behavior: optimized layout and Figure 10. Est add of a capacitance of 100 nF

ESD behavior: measurement conditions (with coupling capacitance)

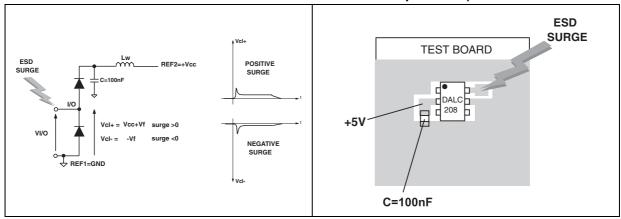
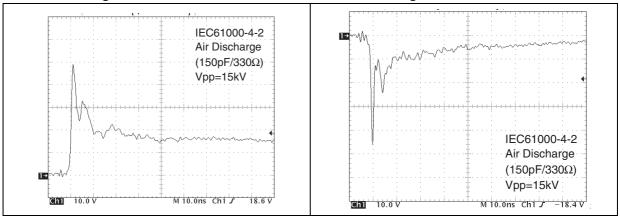


Figure 11. Remaining voltage after the DALC208SC6 during positive ESD surge

Figure 12. Remaining voltage after the DALC208SC6 during negative ESD surge



#### **Important**

A precaution to take is to put the protection device as close as possible to the disturbance source (generally the connector).

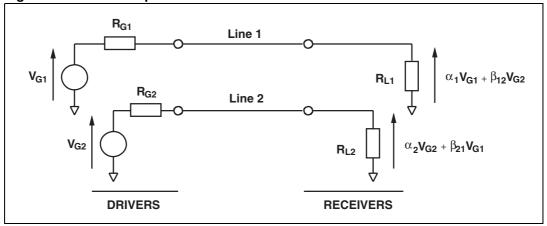
Note: The measurements have been done with the DALC208SC6 in open circuit.

DALC208 Crosstalk behavior

## 3 Crosstalk behavior

### 3.1 Crosstalk phenomena

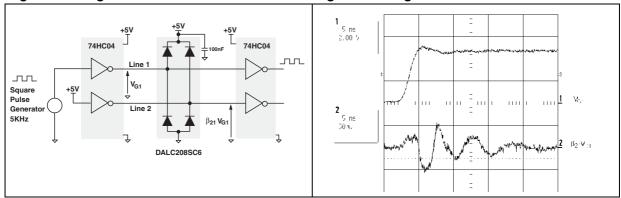
Figure 13. Crosstalk phenomena



The crosstalk phenomenon is due to the coupling between 2 lines. The coupling factor ( $\beta$ 12 or  $\beta$ 21) increases when the gap across lines decreases, particularly in silicon dice. In the example in *Figure 13* the expected signal on load R<sub>L2</sub> is  $\alpha_2 V_{G2}$ , in fact the real voltage at this point has got an extra value  $\beta_{21}V_{G1}$ . This part of the  $V_{G1}$  signal represents the effect of the crosstalk phenomenon of line 1 on line 2. This phenomenon has to be taken into account when the drivers impose fast digital data or high frequency analog signals in the disturbing line. The disturbed line will be more affected if it works with low voltage signal or high load impedance (few  $k\Omega$ ). The following sections give the value of both digital and analog crosstalk.

## 3.2 Digital crosstalk

Figure 14. Digital crosstalk measurements Figure 15. Digital crosstalk results



*Figure 14* shows the measurement circuit used to quantify the crosstalk effect in a classical digital application. *Figure 15* shows that in such a condition: signal from 0 V to 5 V and a rise time of 5 ns, the impact on the disturbed line is less than 100mV peak to peak. No data disturbance was noted on the concerned line. The same results were obtained with falling edges.

Crosstalk behavior DALC208

Note:

The measurements have been done in the worst case i.e. on two adjacent cells (I/O1 and I/O4).

## 3.3 Analog crosstalk

Figure 16. Analog crosstalk measurements

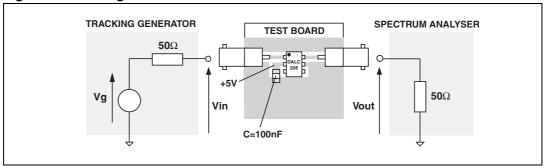
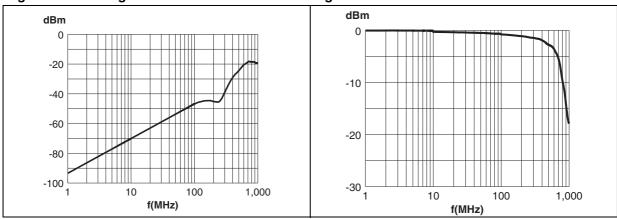


Figure 16 shows the measurement circuit for the analog application. For the usual frequency range of analog signals (up to 100MHz) the effect on disturbed line is less than -45 dBm. See Figure 17.

Figure 17. Analog crosstalk results





As the DALC208SC6 is designed to protect high speed data lines, it must ensure a good transmission of operating signals. The attenuation curve give such an information.

*Figure 18* shows that the DALC208SC6 is well suitable for data line transmission up to 100 Mbit/s while it works as a filter for undesirable signals such as GSM carrier (900 MHz).

# 4 Application examples

Figure 19. Video line protection

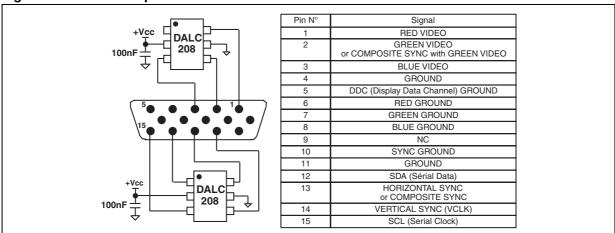


Figure 20. T1/E1 protection

Figure 21. USB port protection

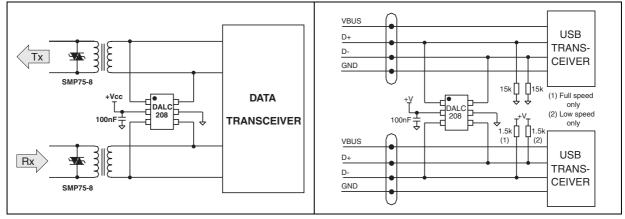
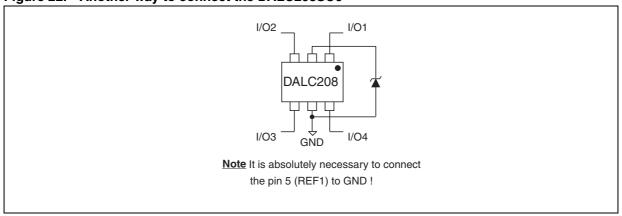


Figure 22. Another way to connect the DALC208SC6

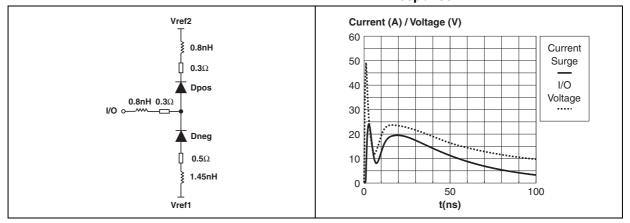


PSpice model DALC208

# 5 PSpice model

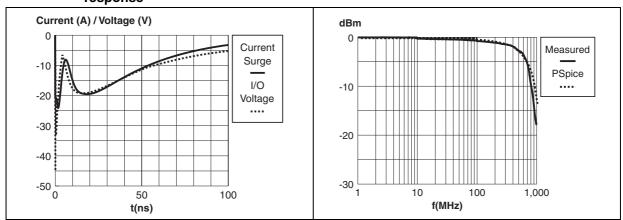
*Figure 23* shows the PSpice model of one DALC208SC6 cell. In this model, the diodes are defined by the PSpice parameters given in *Table 4*.

Figure 23. PSpice model of one DALC208SC6 Figure 24. PSpice model simulation: surge > 0 cell IEC 61000-4-2 contact discharge response



Note: This simulation model is available only for an ambient temperature of 27 °C. The simulations done (Figure 24, Figure 25 and Figure 26) show that the PSpice model is close to the product behavior.

Figure 25. PSpice model simulation: surge < 0 Figure 26. Attenuation comparison IEC61000-4-2 contact discharge response



DALC208 PSpice model

Table 4. PSpice parameter

Parameter	D <sub>POS</sub>	D <sub>NEG</sub>	
BV	9	9	
CIO	7р	7р	
IBV	IBV 1u		
IKF	28.357E-3	1000	
IS	118.78E-15	5.6524E-9	
ISR	100E-12	472.3E-9	
M	0.3333	0.3333	
N	1.3334	2.413	
NR	2	2	
RS	0.68377	0.71677	
VJ 0.6		0.6	

Package information DALC208

## 6 Package information

#### Epoxy meets UL94, V0

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at <a href="https://www.st.com">www.st.com</a>.

Table 5. SOT23-6L dimensions

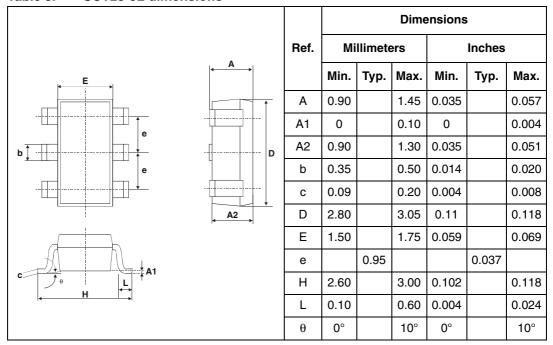
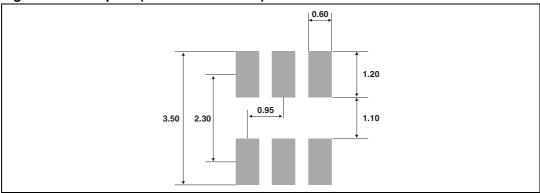


Figure 27. Footprint (dimensions in mm)



# 7 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Packing mode
DALC208SC6	DALC	SOT23-6L	16.7 mg	3000	Tape and reel

# 8 Revision history

Table 7. Document revision history

Date	Revision	Changes
Feb-2002	5C	Last update.
28-Oct-2004	6	SOT23-6L package dimensions change for reference "D" from 3.0 millimeters (0.118 inches) to 3.05 millimeters (0.120 inches).
20-Mar-2008	7	Reformatted to current standard. Added ECOPACK paragraph.

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